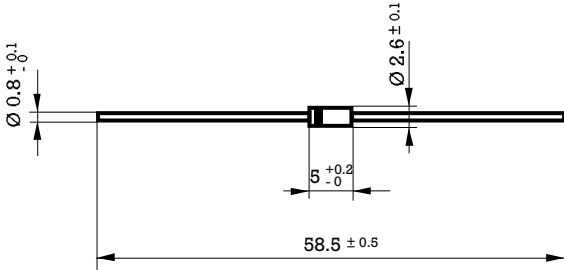



1 Amp. Glass Passivated Avalanche Ultrafast Recovery Rectifier

<p>Dimensions in mm.</p>  <p>Mounting instructions</p> <ol style="list-style-type: none"> 1. Min. distance from body to soldering point, 4 mm. 2. Max. solder temperature, 350 °C. 3. Max. soldering time, 3.5 sec. 4. Do not bend lead at a point closer than 2 mm. to the body. 	<p>DO-41 (Plastic)</p> <p>Voltage 50 to 600 V.</p> <p>Current 1 A at 55 °C.</p> 
	<ul style="list-style-type: none"> • Glass Passivated Junction • High current capability • The plastic material carries U/L recognition 94 V-0 • Terminals: Axial Leads • Polarity: Color band denotes cathode

Maximum Ratings, according to IEC publication No. 134

		EGP10A	EGP10B	EGP10D	EGP10F	EGP10G	EGP10J
V_{RRM}	Peak Recurrent reverse voltage (V)	50	100	200	300	400	600
V_{RMS}	Maximum RMS voltage	35	70	140	210	280	420
V_{DC}	Maximum DC blocking voltage	50	100	200	300	400	600
$I_{F(AV)}$	Forward current at $T_{amb} = 55\text{ °C}$	1 A					
I_{FRM}	Recurrent peak forward current	10 A					
I_{FSM}	8.3 ms. peak forward surge current (Jedec Method)	30 A					
t_{rr}	Max. reverse recovery time from $I_F = 0.5\text{ A}$; $I_R = 1\text{ A}$; $I_{RR} = 0.25\text{ A}$	50 ns					
C_j	Typical Junction Capacitance at 1 MHz and reverse voltage of $4V_{DC}$	15 pF					
T_j	Operating temperature range	- 65 to + 150 °C					
T_{stg}	Storage temperature range	- 65 to + 150 °C					
E_{RSM}	Maximum non repetitive peak reverse avalanche energy. $I_R = 0.5\text{ A}$; $T_j = 25\text{ °C}$	20 mJ					

Electrical Characteristics at $T_{amb} = 25\text{ °C}$

V_F	Max. forward voltage drop at $I_F = 1\text{ A}$	0.95 V	1.25 V
I_R	Max. reverse current at V_{RRM} at 25 °C at 150 °C	5 $\mu\text{ A}$ 50 $\mu\text{ A}$	
R_{thj-a}	Max. thermal resistance (l = 10 mm.)	60 °C/W	

Rating And Characteristic Curves

